

Features

November 2006

- Synchronizes to 8 kHz, 2.048 MHz, 8.192 MHz or 16.384 MHz
- Provides a range of output clocks:
 - 65.536 MHz TDM clock locked to the input reference
 - General purpose 25 MHz fan-out to 6 outputs locked to the external crystal or oscillator
 - General purpose 125 MHz and 66 MHz or 100 MHz locked to the external crystal or oscillator
- Provides DPLL lock and reference fail indication
- Automatic free run mode on reference fail
- DPLL bandwidth of 922 Hz for all rates of input reference and 58 Hz for an 8 kHz input reference
- Less than 5 psec_{rms} on 25 MHz outputs, and less than 0.6 nspp intrinsic jitter on the all other outputs
- Minimal input to output and output to output skew
- 25 MHz external master clock source: clock oscillator or crystal
- Simple hardware control interface

Ordering Information

ZL30110LDE	32 Pin QFN	Tubes Bake & Dry Pack
ZL30110LDE1	32 Pin QFN*	Tubes Bake & Dry Pack
*Pb Free Matte Tin		
-40°C to +85°C		

Applications

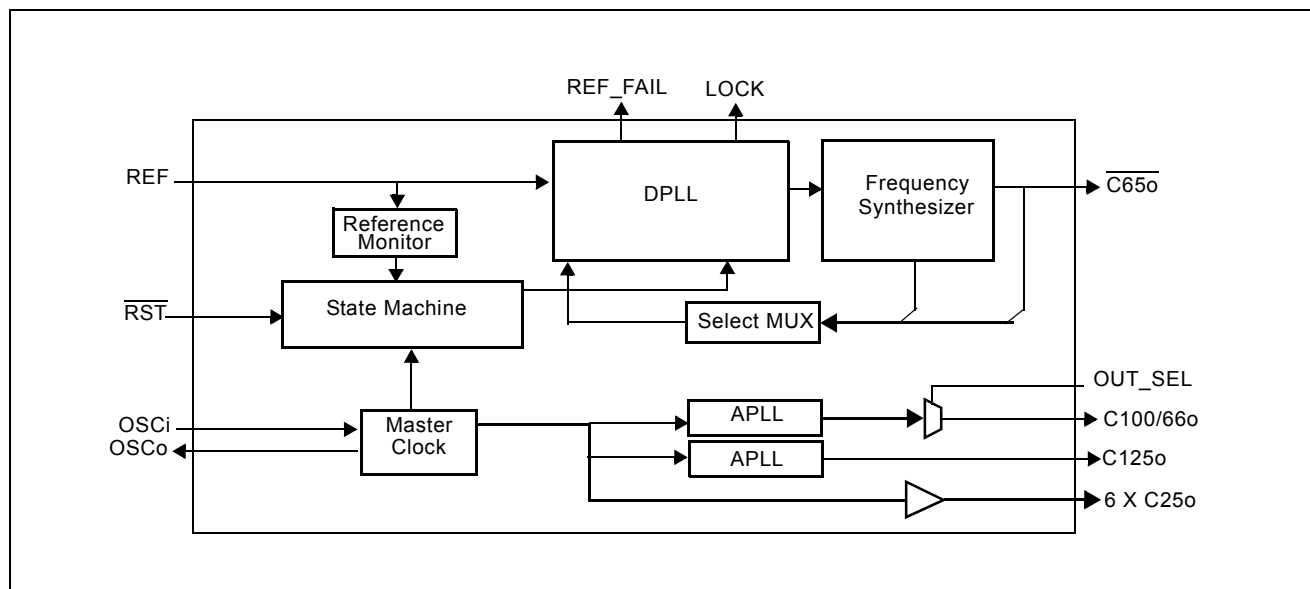
- Clock rate conversion PLL for Telecommunication Equipment
- Small/Medium Enterprise Router / Gateway
- Broadband access (xPON/xDSL) CPE gateway

Description

The ZL30110 clock rate conversion digital phase-locked loop (DPLL) provides accurate and reliable frequency conversion.

The ZL30110 generates a range of clocks that are either locked to the input reference or locked to the external crystal or oscillator.

In the locked mode, the reference input is continuously monitored for a failure condition. In the event of a failure, the DPLL continues to provide a stable free running clock ensuring system reliability.


Figure 1 - Functional Block Diagram

1.0 Physical Description

1.1 Pin Connections

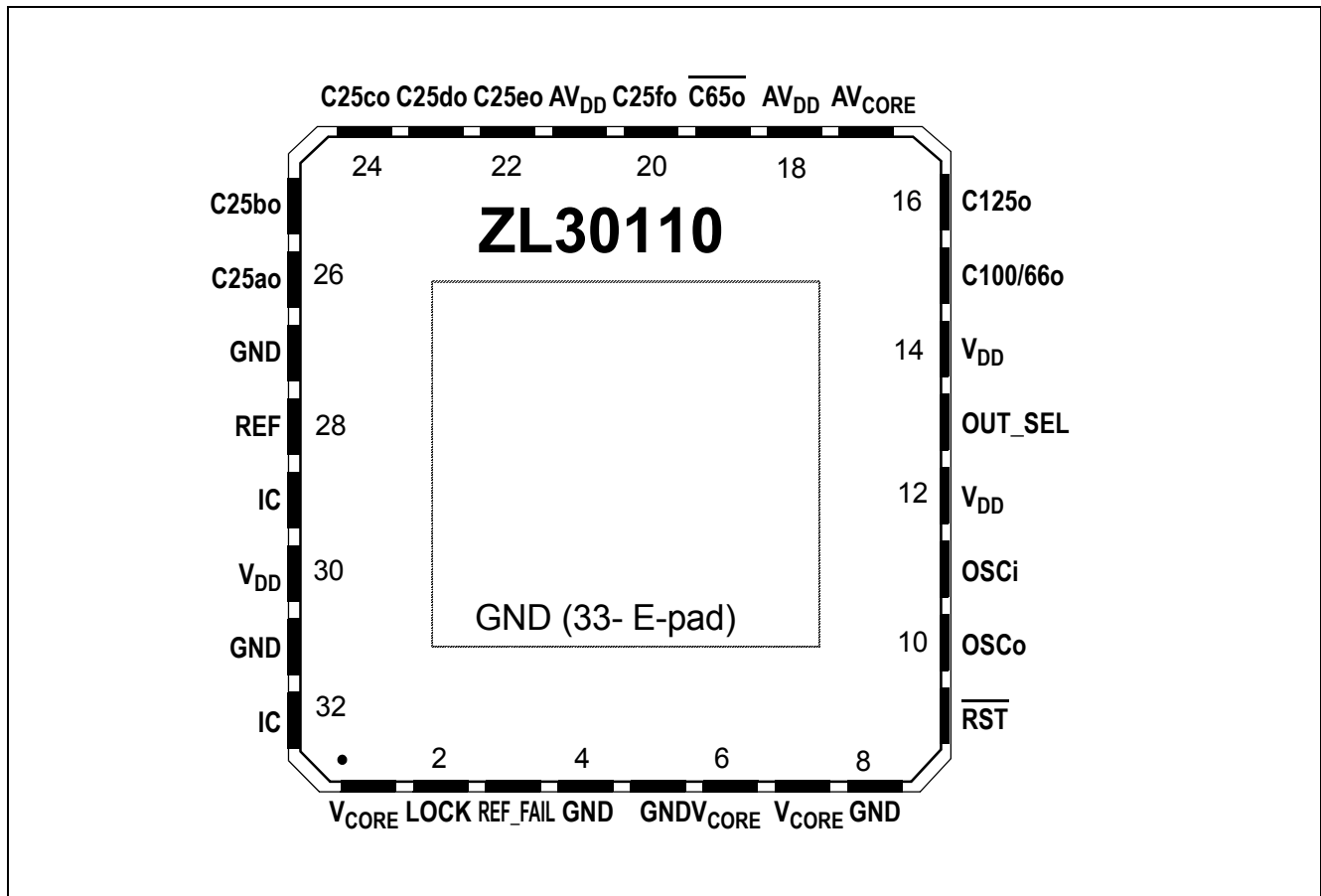


Figure 2 - Pin Connections (32 pin 5 mm X 5 mm QFN with E-pad)

Table of Contents

1.0 Physical Description	2
1.1 Pin Connections	2
1.2 Pin Description	6
2.0 Functional Description	8
2.1 Reference Monitor	8
2.2 Digital Phase Lock Loop (DPLL)	9
2.3 Frequency Synthesizers	9
2.4 State Machine	9
2.5 APLL	9
2.6 Master Clock	9
3.0 DPLL Modes of Operation	10
3.1 Freerun Mode	10
3.2 Normal Mode	10
4.0 Measures of Performance	11
4.1 Jitter	11
4.2 Jitter Generation (Intrinsic Jitter)	11
4.3 Jitter Transfer	11
4.4 Lock Time	11
5.0 Applications	12
5.1 Power Supply Decoupling	12
5.2 Master Clock	12
5.2.1 Clock Oscillator	12
5.2.2 Crystal Oscillator	13
5.3 Power Up Sequence	14
5.4 Reset Circuit	14
6.0 Characteristics	15
6.1 AC and DC Electrical Characteristics	15
6.2 Performance Characteristics	18

List of Figures

Figure 1 - Functional Block Diagram	1
Figure 2 - Pin Connections (32 pin 5 mm X 5 mm QFN with E-pad)	2
Figure 3 - Reference Monitor Circuit	8
Figure 4 - DPLL Mode Switching	10
Figure 5 - Clock Oscillator Circuit	12
Figure 6 - Power-Up Reset Circuit	14
Figure 7 - Timing Parameter Measurement Voltage Levels	16
Figure 8 - Input to Output Timing for Synchronous Clock	17
Figure 9 - Asynchronous Clocks Input to Output Timing	18

List of Tables

Table 1 - Clock Oscillator Specification 12

Table 2 - Crystal Oscillator Specification 13

1.2 Pin Description

Pin #	Name	I/O Type	Description
Input Reference			
28	REF	I	Reference (LVCMOS, Schmitt Trigger). This is the input reference source used for synchronization. One of four possible frequencies may be used: 8 kHz, 2.048 MHz, 8.192 MHz or 16.384 MHz. This pin is internally pulled down to GND.
Master Clock			
11	OSCi	I	Oscillator Master Clock (Input). For crystal operation, a 25 MHz crystal is connected from this pin to OSCo. For clock oscillator operation, this pin must be connected to a clock source.
10	OSCo	O	Oscillator Master Clock (LVCMOS). For crystal operation, a 25 MHz crystal is connected from this pin to OSCi. This output is not suitable for driving other devices (see C25o output pin for support of such function). For clock oscillator operation, this pin must be left unconnected.
Control and Status			
9	$\overline{\text{RST}}$	I	Reset (LVCMOS, Schmitt Trigger). A logic low at this input resets the device. On power up, the $\overline{\text{RST}}$ pin must be held low for a minimum of 300 ns after the power supply pins have reached the minimum supply voltage. When the $\overline{\text{RST}}$ pin goes high, the device will transition into a Reset state for 3 ms. In the Reset state all outputs will be forced into high impedance.
13	OUT_SEL	I	Output Select (LVCMOS, Schmitt Trigger). This input pin selects the output clock frequency of the C100/66o, a logic low selects the 100 MHz output, while logic high selects the 66 MHz output clock.
3	REF_FAIL	O	Reference Failure Indicator (LVCMOS). A logic high at this pin indicates that the REF reference frequency is exhibiting abrupt phase or frequency change.
2	LOCK	O	Lock Indicator (LVCMOS). This output goes to a logic high when the PLL is frequency locked to a valid input reference.
Output Clocks			
19	$\overline{\text{C65o}}$	O	Clock 65.536 MHz (LVCMOS). This output is used in general TDM applications. The falling edge of this clock is aligned with rising edge of the input reference (REF).
26	C25ao	O	Clock 25 MHz (LVCMOS). This is a buffered external oscillator clock, the phase and frequency accuracy of this output tracks that of the external crystal or oscillator.
25	C25bo	O	Clock 25 MHz (LVCMOS). This is a buffered external oscillator clock, the phase and frequency accuracy of this output tracks that of the external crystal or oscillator.
24	C25co	O	Clock 25 MHz (LVCMOS). This is a buffered external oscillator clock, the phase and frequency accuracy of this output tracks that of the external crystal or oscillator.
23	C25do	O	Clock 25 MHz (LVCMOS). This is a buffered external oscillator clock, the phase and frequency accuracy of this output tracks that of the external crystal or oscillator.

Pin #	Name	I/O Type	Description
22	C25eo	O	Clock 25 MHz (LVCMOS). This is a buffered external oscillator clock, the phase and frequency accuracy of this output tracks that of the external crystal or oscillator.
20	C25fo	O	Clock 25 MHz (LVCMOS). This is a buffered external oscillator clock, the phase and frequency accuracy of this output tracks that of the external crystal or oscillator.
15	C100/66o	O	Clock 100 MHz or 66 MHz (LVCMOS). This is 100 MHz or 66 MHz rate converted clocks off the 25 MHz fixed frequency external oscillator, the phase and frequency accuracy of this output tracks that of the external crystal or oscillator device.
16	C125o	O	Clock 125 MHz (LVCMOS). This is 125 MHz rate converted clock off the 25 MHz fixed frequency external oscillator, the phase and frequency accuracy of this output tracks that of the external crystal or oscillator device.
Miscellaneous			
29	IC		Internal Connection. Connect to VDD.
32	IC		Internal Connection. Connect to VDD.
Power and Ground			
12	V _{DD}		Positive Supply Voltage. +3.3 V _{DC} nominal.
14	V _{DD}		Positive Supply Voltage. +3.3 V _{DC} nominal.
30	V _{DD}		Positive Supply Voltage. +3.3 V _{DC} nominal.
1	V _{CORE}		Positive Supply Voltage. +1.8 V _{DC} nominal.
6	V _{CORE}		Positive Supply Voltage. +1.8 V _{DC} nominal.
7	V _{CORE}		Positive Supply Voltage. +1.8 V _{DC} nominal.
17	AV _{CORE}		Positive Analog Supply Voltage. +1.8 V _{DC} nominal.
18	AV _{DD}		Positive Analog Supply Voltage. +3.3 V _{DC} nominal.
21	AV _{DD}		Positive Analog Supply Voltage. +3.3 V _{DC} nominal.
4	GND		Ground. 0 V.
5	GND		Ground. 0 V.
8	GND		Ground. 0 V.
27	GND		Ground. 0 V.
31	GND		Ground. 0 V.
33 E-pad	GND		Internal Connection. Package E-pad, this pin is internally connected to device GND, it should be connected to GND.

2.0 Functional Description

2.1 Reference Monitor

The input reference is monitored by two reference monitor blocks. The block diagram of reference monitoring is shown in Figure 3. The reference frequency is detected and the clock is continuously monitored for two independent criteria that indicate abnormal behavior of the reference signal, for example; loss of clock or excessive level of frequency error. To ensure proper operation of the reference monitor circuit, the minimum input pulse width restriction of 15 nsec must be observed.

- **Reference Frequency Detector (RFD):** This detector determines whether the frequency of the reference clock is 8 kHz, 2.048 MHz, 8.192 MHz or 16.384 MHz and provides this information to the various monitor circuits and the phase detector circuit of the DPLL.
- **Coarse Frequency Monitor (CFM):** This circuit monitors the reference frequency over intervals of approximately 30 μ s to quickly detect large frequency changes.
- **Single Cycle Monitor (SCM):** This detector checks the period of a single clock cycle to detect large phase hits or the complete loss of the clock.

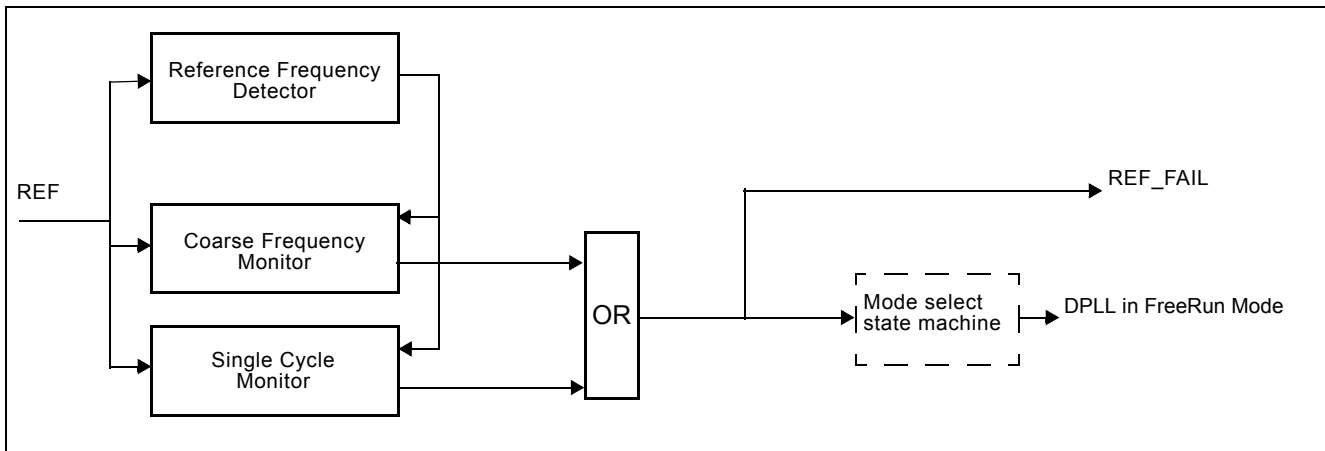


Figure 3 - Reference Monitor Circuit

Exceeding the thresholds of any of the monitors forces the corresponding REF_FAIL pin to go high. The single cycle and coarse frequency failure flags force the DPLL into FreeRun mode.

2.2 Digital Phase Lock Loop (DPLL)

The DPLL of the ZL30110 consists of a phase detector, a loop filter and a digitally controlled oscillator.

Phase Detector - the phase detector compares the input reference signal to the feedback signal and provides an error signal corresponding to the phase difference between the two.

Loop Filter - the loop filter is similar to a first order low pass filter with a bandwidth of 922 Hz. For stability reasons, the loop filter bandwidth for an 8 kHz reference is limited to a maximum of 58 Hz.

Digitally Controlled Oscillator (DCO) - the DCO receives the filtered signal from the Loop Filter, and based on its value, generates a corresponding digital output signal. The synchronization method of the DCO is dependent on the state of the ZL30110.

In Normal Mode, the DCO provides an output signal which is frequency and phase locked to the selected input reference signal.

In Freerun Mode, the DCO is free running with an accuracy equal to the accuracy of the OSCi 25 MHz source.

Lock Indicator - the lock detector monitors if the output value of the phase detector is within the phase-lock-window for a certain time. The selected phase-lock-window guarantees the stable operation of the LOCK pin with maximum network jitter and wander on the reference input. If the DPLL goes into FreeRun mode, the LOCK pin will initially stay high for 0.1 s. If at that point the DPLL is still in FreeRun mode, the LOCK pin will go low. In Freerun mode the LOCK pin will go low immediately.

2.3 Frequency Synthesizers

The output of the DCO is used by the frequency synthesizer to generate the output clock which is synchronized to the inputs (REF). The frequency synthesizer uses digital techniques to generate output clock and advanced noise shaping techniques to minimize the output jitter. The clock and frame pulse outputs have limited driving capability and should be buffered when driving high capacitance loads.

2.4 State Machine

As shown in Figure 1, the state machine controls the DPLL.

2.5 APLL

The ZL30110 employ two Analog PLLs as a clock multiplying and rate conversion engine. One APLL is used to multiply the master clock (OSCi) to 125 MHz, a second APLL is used to convert the master clock (OSCi) to 100 MHz or 66 MHz clock.

2.6 Master Clock

The ZL30110 can use either a clock or crystal as the master timing source. For recommended master timing circuits, see the Applications - Master Clock section.

3.0 DPLL Modes of Operation

The ZL30110 has two possible modes of operation; Normal, and Freerun. The ZL30110 starts up in Freerun mode, it automatically transitions to Normal mode if a valid reference is available and transitions to Freerun mode if the reference fails.

3.1 Freerun Mode

Freerun mode is typically used when an independent clock source is required or immediately following system power-up before synchronization is achieved.

In Freerun mode, the ZL30110 provides timing and synchronization signals which are based on the master clock frequency (supplied to OSCi pin) only and are not synchronized to the reference input signals.

The accuracy of the output clock is equal to the accuracy of the master clock (OSCi). So if a ± 32 ppm output clock is required, the master clock must also be ± 32 ppm. See Applications - Section 5.2, "Master Clock".

Freerun Mode is also used for short durations while system synchronization is temporarily disrupted. The accuracy of the output clock during these input reference disruptions is better than the accuracy of the master clock (OSCi), but it is off compared to the reference before disruptions.

3.2 Normal Mode

Normal mode is typically used when a system clock source, synchronized to the network is required. In Normal mode, the ZL30110 provides timing synchronization signals, which are synchronized to the input (REF). The input reference signal may have a nominal frequency of 8 kHz, 2.048 MHz, 8.192 MHz or 16.384 MHz. The frequency of the reference inputs are automatically detected by the reference monitors.

When the ZL30110 comes out of RESET it will initially go into Freerun mode and generate a clock with the accuracy of its freerunning local oscillator (see Figure 4). If the ZL30110 determines that its selected reference is disrupted (see Figure 3), it will remain in Freerun until the selected reference is no longer disrupted. If the ZL30110 determines that the reference is not disrupted (see Figure 3) then the state machine will cause the DPLL to recover from Freerun and transition to Normal mode.

When the ZL30110 is operating in Normal mode, if it determines that the input reference is disrupted (Figure 3) then its state machine will cause it to automatically go to Freerun mode. When the ZL30110 determines that its selected reference is not disrupted then the state machine will cause the DPLL to recover from Freerun and transition to Normal mode.

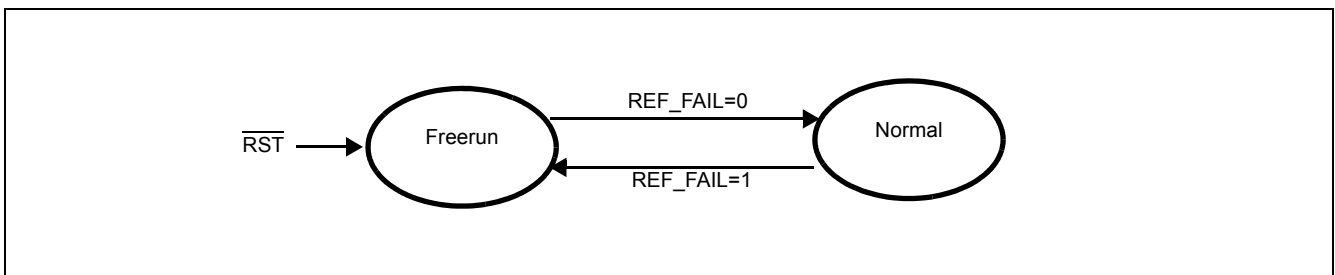


Figure 4 - DPLL Mode Switching

4.0 Measures of Performance

The following are some PLL performance indicators and their corresponding definitions.

4.1 Jitter

Timing jitter is defined as the high frequency variation of the clock edges from their ideal positions in time. Wander is defined as the low-frequency variation of the clock edges from their ideal positions in time. High and low frequency variation imply phase oscillation frequencies relative to some demarcation frequency. (Often 10 Hz or 20 Hz for DS1 or E1, higher for SONET/SDH clocks.) Jitter parameters given in this data sheet are total timing jitter numbers, not cycle-to-cycle jitter.

4.2 Jitter Generation (Intrinsic Jitter)

Jitter generation is the measure of the jitter produced by the PLL and is measured at its output. It is measured by applying a reference signal with no jitter to the input of the device, and measuring its output jitter. Jitter is usually measured with various band limiting filters depending on the applicable standards.

4.3 Jitter Transfer

Jitter transfer or jitter attenuation refers to the magnitude of jitter at the output of a device for a given amount of jitter at the input of the device. Input jitter is applied at various amplitudes and frequencies, and output jitter is measured with various filters depending on the applicable standards.

4.4 Lock Time

This is the time it takes the PLL to frequency lock to the input signal. Phase lock occurs when the input signal and output signal are aligned in phase with respect to each other within a certain phase distance (not including jitter). Lock time is affected by many factors which include:

- initial input to output phase difference
- initial input to output frequency difference
- PLL loop filter bandwidth

The presence of input jitter makes it difficult to define when the PLL is locked as it may not be able to align its output to the input within the required phase distance, dependent on the PLL bandwidth and the input jitter amplitude and frequency.

5.0 Applications

This section contains ZL30110 application specific details for power supply decoupling, reset operation, clock and crystal operation.

5.1 Power Supply Decoupling

Jitter levels on the ZL30110 output clocks may increase if the device is exposed to excessive noise on its power pins. For optimal jitter performance, the ZL30110 device should be isolated from noise on power planes connected to its 3.3 V and 1.8 V supply pins. For recommended common layout practices, refer to Zarlink Application Note ZLAN-178.

5.2 Master Clock

The ZL30110 can use either a clock or crystal as the master timing source.

5.2.1 Clock Oscillator

When selecting a clock oscillator, numerous parameters must be considered. This includes absolute frequency, frequency change over temperature, output rise and fall times, output levels, duty cycle and phase noise.

The output clock should be connected directly (not AC coupled) to the OSCi input of the ZL30110, and the OSCo output should be left open as shown in Figure 5.

1	Frequency	25 MHz
2	Tolerance	as required (better than +/-50ppm)
3	Rise & fall time	< 8 ns
4	Duty cycle	40% to 60%

Table 1 - Clock Oscillator Specification

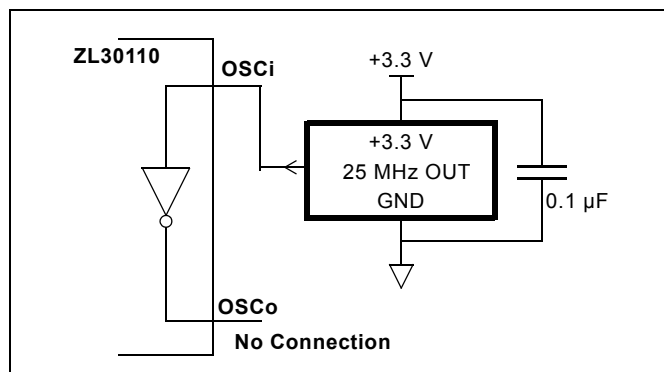


Figure 5 - Clock Oscillator Circuit

5.2.2 Crystal Oscillator

Alternatively, a Crystal Oscillator may be used. The accuracy of a crystal oscillator depends on the crystal tolerance as well as the load capacitance tolerance. Typically, for a 25 MHz crystal specified with a 32 pF load capacitance, each 1 pF change in load capacitance contributes approximately 9 ppm to the frequency deviation. Consequently, capacitor tolerances and stray capacitances have a major effect on the accuracy of the oscillator frequency.

The crystal should be a fundamental mode type - not an overtone. The fundamental mode crystal permits a simpler oscillator circuit with no additional filter components and is less likely to generate spurious responses. A typical crystal oscillator specification is shown in Table 2.

1	Frequency	25 MHz
2	Tolerance	as required (better than +/-50ppm)
3	Oscillation mode	fundamental
4	Resonance mode	parallel
5	Load capacitance	as required
6	Maximum series resistance	50 Ω

Table 2 - Crystal Oscillator Specification

5.3 Power Up Sequence

The ZL30110 requires that the 3.3 V supply is not powered up after the 1.8 V supply. This is to prevent the risk of latch-up due to the presence of protection diodes in the IO pads.

Two options are given:

1. Power-up the 3.3 V supply fully first, then power up the 1.8 V supply
2. Power up the 3.3 V supply and the 1.8 V supply simultaneously, ensuring that the 3.3 V supply is never lower than a few hundred millivolts below the 1.8 V supply (e.g., by using a schottky diode or controlled slew rate)

5.4 Reset Circuit

A simple power up reset circuit with about a 60 μ s reset low time is shown in Figure 6. Resistor R_P is for protection only and limits current into the $\overline{\text{RST}}$ pin during power down conditions. The reset low time is not critical but should be greater than 300 ns.

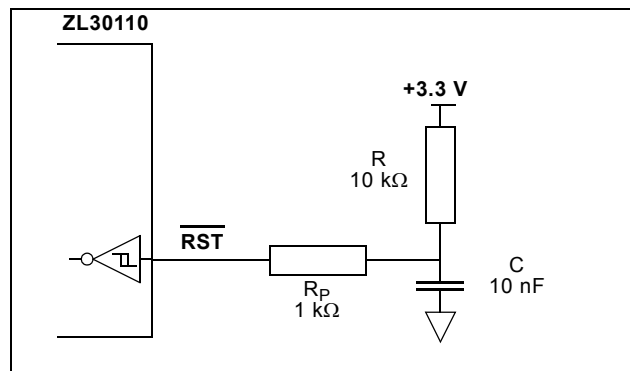


Figure 6 - Power-Up Reset Circuit

6.0 Characteristics

6.1 AC and DC Electrical Characteristics

Absolute Maximum Ratings*

	Parameter	Symbol	Min.	Max.	Units
1	Supply voltage	V_{DD_R}	-0.5	4.6	V
2	Core supply voltage	V_{CORE_R}	-0.5	2.5	V
3	Voltage on any digital pin	V_{PIN}	-0.5	6	V
4	Voltage on OSCi and OSCo pin	V_{OSC}	-0.3	$V_{DD} + 0.3$	V
5	Current on any pin	I_{PIN}		30	mA
6	Storage temperature	T_{ST}	-55	125	°C
7	ESD rating	V_{ESD}		2k	V

* Exceeding these values may cause permanent damage. Functional operation under these conditions is not implied.

* Voltages are with respect to ground (GND) unless otherwise stated.

Recommended Operating Conditions*

	Characteristics	Sym.	Min.	Typ.	Max.	Units
1	Supply voltage	V_{DD}	3.1	3.3	3.5	V
2	Core supply voltage	V_{CORE}	1.7	1.8	1.9	V
3	Operating temperature	T_A	-40	25	85	°C
4	Input Voltage	V_I	0	3.3	3.5	V

* Voltages are with respect to ground (GND) unless otherwise stated.

DC Electrical Characteristics*

	Characteristics	Sym.	Min.	Max.	Units	Notes
1	Supply current	I_{DD}		115	mA	All Outputs loaded with 30 pf
2	Core supply current	I_{CORE}		20	mA	All Outputs loaded with 30 pf
3	Schmitt trigger Low to High threshold point	V_{CIH}	1.43	1.85	V	
4	Schmitt trigger High to Low threshold point	V_{CIL}	0.8	1.1	V	
5	Input leakage current	I_{IL}	-105	105	μA	$V_I = V_{DD}$ or 0 V

DC Electrical Characteristics*

	Characteristics	Sym.	Min.	Max.	Units	Notes
6	High-level output voltage	V_{OH}	2.4		V	$I_{OH} = 8\text{ mA}$ for clock outputs, 4 mA for status outputs
7	Low-level output voltage	V_{OL}		0.4	V	$I_{OL} = 8\text{ mA}$ for clock outputs, 4 mA for status outputs

* Supply voltage and operating temperature are as per Recommended Operating Conditions.

* Voltages are with respect to ground (GND) unless otherwise stated.

AC Electrical Characteristics* - Timing Parameter Measurement Voltage Levels (see Figure 7).

	Characteristics	Sym.	CMOS	Units
1	Threshold Voltage	V_T	$0.5 \times V_{DD}$	V
2	Rise and Fall Threshold Voltage High	V_{HM}	$0.7 \times V_{DD}$	V
3	Rise and Fall Threshold Voltage Low	V_{LM}	$0.3 \times V_{DD}$	V

* Supply voltage and operating temperature are as per Recommended Operating Conditions.

* Voltages are with respect to ground (GND) unless otherwise stated.

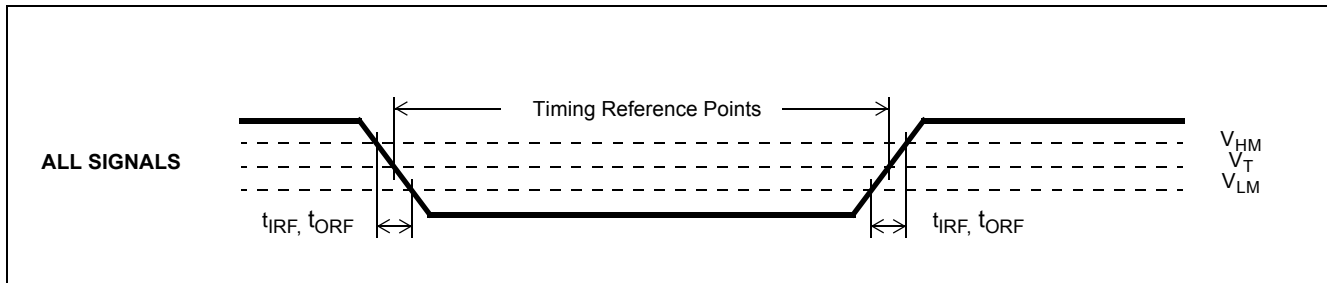


Figure 7 - Timing Parameter Measurement Voltage Levels

AC Electrical Characteristics* - Timing for input reference (see Figure 8).

	Characteristics	Symbol	Min.	Typ.	Max.	Units
1	8 kHz reference period	t_{REF8kP}	120	125	128	μs
2	2.048 MHz reference period	t_{REF2P}	263	488	712	ns
3	8.192 MHz reference period	t_{REF8P}	63	122	175	ns
4	16.384 MHz reference period	t_{REF16P}	38	61	75	ns
5	reference pulse width high or low	t_{REFW}	15			ns

* Supply voltage and operating temperature are as per Recommended Operating Conditions.

* Period Min/Max values are the limits to avoid a single-cycle fault detection. Short-term and long-term average periods must be within +/-130 ppm limit.

AC Electrical Characteristics* - Input to output timing for synchronous clock (see Figure 8).

	Characteristics	Symbol	Min.	Max.	Units
1	8 kHz reference input to $\overline{C65o}$ delay	t_{REF8_C65D}	-0.7	6.7	ns
2	2.048 MHz reference input to $\overline{C65o}$ delay	t_{REF2_C65D}	1.5	9.6	ns
3	8.192 MHz reference input to $\overline{C65o}$ delay	t_{REF8_C65D}	2.1	9.2	ns
4	16.384 MHz reference input to $\overline{C65o}$ delay	t_{REF16_C65D}	2.1	9.6	ns
5	$\overline{C65o}$ pulse width low	t_{C65L}	7.0	8.6	ns
6	Output clock rise or fall time	t_{ORF}	1.1	2.3	ns

* Supply voltage and operating temperature are as per Recommended Operating Conditions.

Outputs loaded with 30 pF.

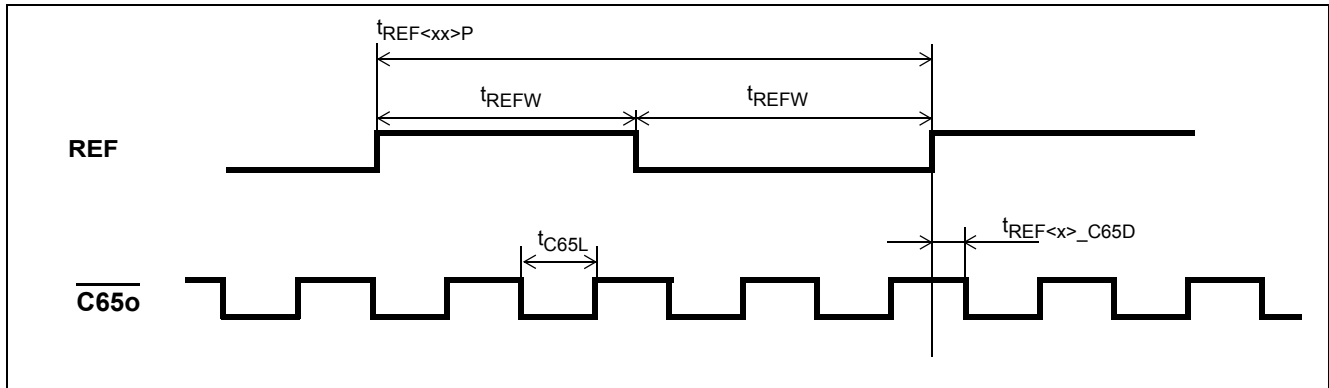


Figure 8 - Input to Output Timing for Synchronous Clock

AC Electrical Characteristics* - Input to output timing for Asynchronous clocks (see Figure 9).

	Characteristics	Symbol	Min.	Max.	Units	Notes
1	25 MHz master clock input to C25a/b/c/d/e/fo delay	t_{M_C25D}	3	14	ns	

* Supply voltage and operating temperature are as per Recommended Operating Conditions.

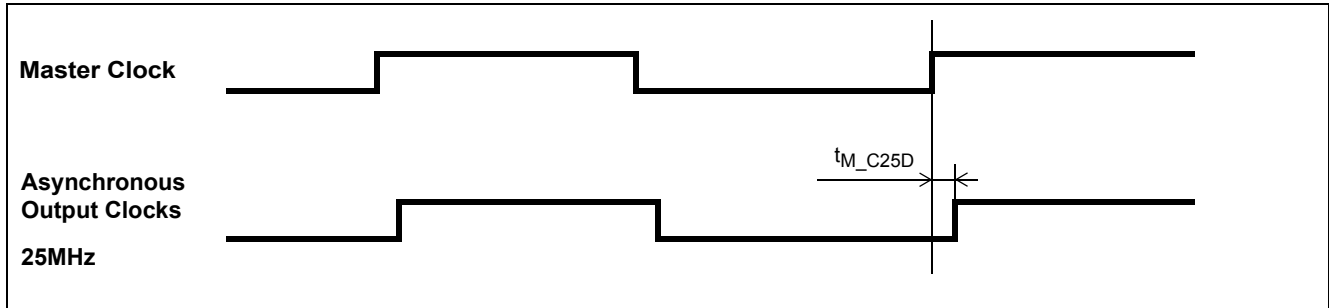


Figure 9 - Asynchronous Clocks Input to Output Timing

AC Electrical Characteristics* - Output timing for Asynchronous clocks (see Figure 9).

	Characteristics	Symbol	Min.	Max.	Units	Notes
1	C25a/b/c/d/e/fo pulse width low**	t_{C25L}	18	22	ns	30 pF output load
2	C125o pulse width low	t_{C125L}	3.2	4.6	ns	25 pF output load
3	C100o pulse width low	t_{C100L}	4.1	5.6	ns	30 pF output load
4	C66o pulse width low	t_{C66L}	6.8	8.0	ns	30 pF output load

* Supply voltage and operating temperature are as per Recommended Operating Conditions.

** Buffered OSCi clock input, characterization data did not account for input clock duty cycle nor rise/fall time degradation.

6.2 Performance Characteristics

Performance Characteristics* - Functional

	Characteristics	Min.	Typ.	Max.	Units	Notes
1	DPLL capture range	-130		+130	ppm	The 25 MHz Master Clock oscillator set at 0.ppm
Lock Time						
2	DPLL 58 Hz Filter			1	s	input reference = 8 kHz, ± 100 ppm frequency offset
3	DPLL 922 Hz Filter			1	s	input reference \neq 8 kHz, ± 100 ppm frequency offset
4	APLL 450 kHz Filter			150	μ s	

* Supply voltage and operating temperature are as per Recommended Operating Conditions.

Performance Characteristics* - Unfiltered Jitter Generation - Pk-Pk

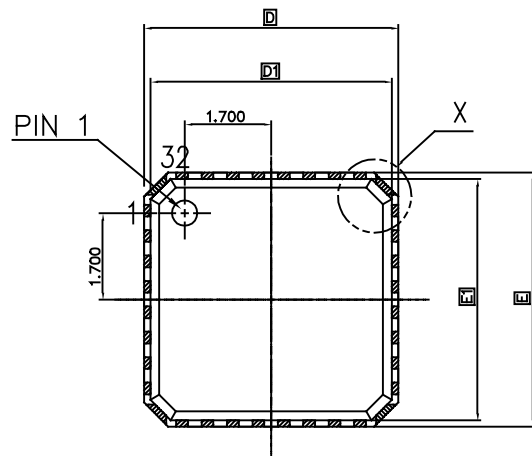
	Characteristics	Max. [ns _{pp}]	Notes
1	C65o (65.536 MHz)	0.60	
3	C25a/b/c/d/e/fo (25 MHz)	0.20	
4	C125o (125 MHz)	0.54	
5	C100o (100 MHz)	0.60	
6	C66o (66 MHz)	0.60	

* Supply voltage and operating temperature are as per Recommended Operating Conditions.

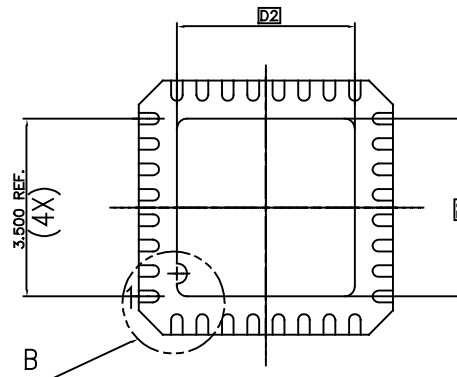
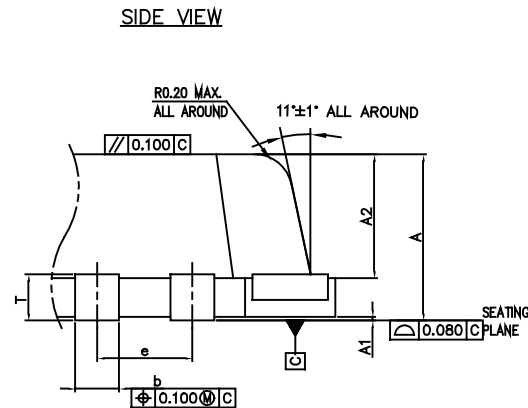
Performance Characteristics* - Filtered Jitter Generation - RMS

	Characteristics	Max. [ps _{rms}]	Notes
1	C25a/b/c/d/e/fo (25 MHz) - (625 kHz - Nyquist)	4	
2	C125o (125 MHz) (625 kHz - Nyquist)	20	

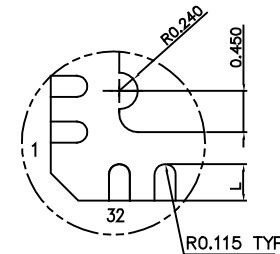
* Supply voltage and operating temperature are as per Recommended Operating Conditions.



TOP VIEW



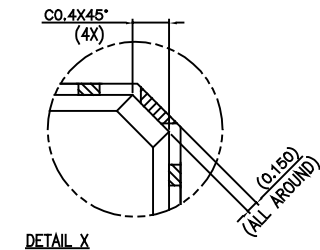
BOTTOM VIEW



DETAIL B

S/N	SYM	DIMENSIONS	REMARKS
1	A	0.850±0.050	OVERALL HEIGHT
2	A1	0.025±0.020	STANDOFF
3	A2	0.650±0.050	CAVITY THICKNESS
4	D	5.000±0.100	PKG. LENGTH
5	D1	4.750±0.100	CAVITY LENGTH
6	D2	3.500±0.050	EXPOSED PAD LENGTH
7	E	5.000±0.100	PKG. WIDTH
8	E1	4.750±0.100	CAVITY WIDTH
9	E2	3.500±0.050	EXPOSED PAD WIDTH
10	L	0.400±0.100	FOOT LENGTH
11	T	0.190~0.245	FRAME THICKNESS
12	b	0.230 ± 0.070 ± 0.060	LEAD WIDTH
13	e	0.500 BASE	LEAD PITCH

COMPLIANT TO JEDEC STANDARD: MO-220



DETAIL X

NOTES:

1. DIMENSIONS & TOLERANCES CONFORM TO ASME Y14.5M, — 1994
2. PIN 1 IDENTIFIER MUST BE ON THE TOP SURFACE OF THE PACKAGE USING AN INDENTATION OR OTHER FEATURE OF THE PACKAGE BODY
3. ALL DIMENSIONS ARE IN MILLIMETERS.
4. PACKAGE WARPAGE MAX 0.08 mm.
5. NOT TO SCALE.
6. DRAWING DOES NOT INCLUDE PLASTIC OR METAL PROTRUSION

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ISSUE	1	2	3	
ACN	CDCA	CDCA	CDCA	
DATE	30-01-2004	15-08-2005	22-08-2005	
APPRD.				



Previous package codes

Package Code LD

Package Outline for Stamped
32 lead QFN (5 x 5mm),
3.7mm DAP (Die Attach Pad)

103364



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